



Low Power Voltage Detector

Features

• Highly accurate: ±1.5% (25 ℃)

• Low power consumption: 1µA @ 3.6V Vcc

• Detect voltage range: 1.8 to 5V in 100mV increments

• Operating voltage range: 1.2V ~ 5.5V

• Operating temperature range: $-40 \, \text{°C}$ to $+85 \, \text{°C}$

• Detect voltage accuracy over temperature: $\pm 2.5\% \times \text{Typ}$

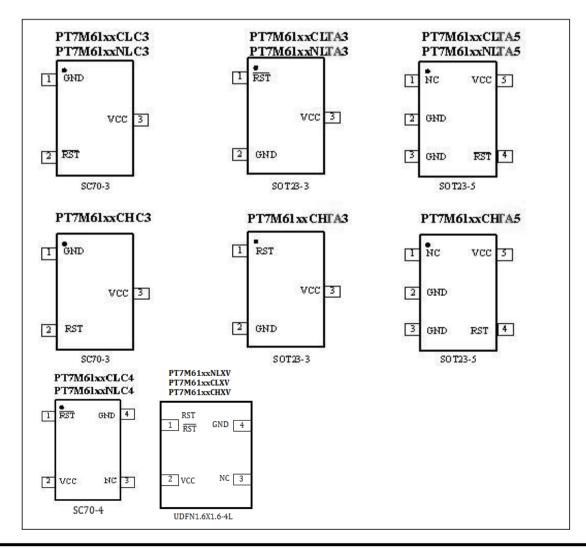
• Output configuration: N-channel open drain or CMOS

Description

The PT7M61xx serials of ultra-low-power voltage detectors monitor battery, power-supply and system voltages. Each circuit includes a precision bandgap reference, a comparator, internally trimmed resistor networks that set specified trip thresholds, and an internal 1% and 5% threshold hysteresis circuit. Output is asserted when V_{CC} falls below the internal V_{TH-} and remains asserted until V_{CC} rises above V_{TH+} ($V_{TH+} = V_{TH-} \times 1.05$). These devices provide excellent circuit reliability and low cost by eliminating external components and adjustments when monitoring nominal system voltages from +1.8V to +5V in 100mV increments. The series are voltage detectors with a propagation delay of 17 μ s.

The family is available with three output stage options: push-pull with active-low output, push-pull with active-high output, and open drain with active-low output. These devices specified over the -40 $^{\circ}$ C to +85 $^{\circ}$ C temperature range.

Pin Configuration





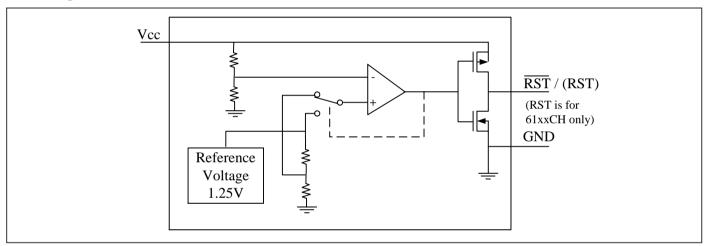


Pin Description

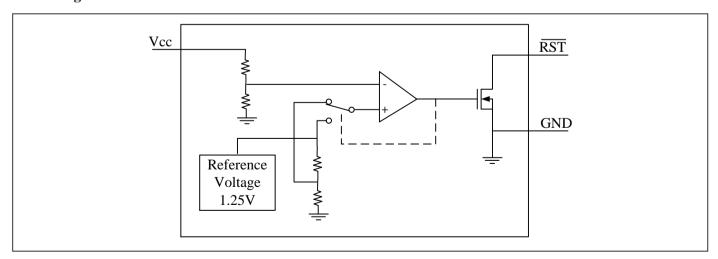
Name	Type	Description					
RST	О	Reset Output (PT7M61xxCL/NL): \overline{RST} is asserted when V_{CC} drops below voltage threshold V_{TH} . Active low.					
RST	0	Reset Output (PT7M61xxCH). RST is asserted when V_{CC} drops below voltage threshold V_{TH} . Active high.					
GND	P	Ground					
V _{CC}	P	Supply Voltage.					

Block Diagram

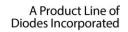
Block Diagram of PT7M61xxCL/CH



Block Diagram of PT7M61xxNL









Maximum Ratings

Storage Temperature	65°C to +150°C
Ambient Temperature with Power Applied	40°C to +85°C
Supply Voltage to Ground Potential (Vcc to GND)	0.3V to +6.0V
DC Input Voltage (All inputs except Vcc and GND)	$-0.3V$ to $V_{CC}+0.3V$
DC Output Current (All outputs)	20mA
Power Dissipation	Depend on package)

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other condi-tions above those indicated in the operational sec-tions of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC Electrical Characteristics

(V_{CC} = 1.2V to 5.5V, T_A = -40~85 °C, unless otherwise noted. Typical values are at T_A = +25 °C)

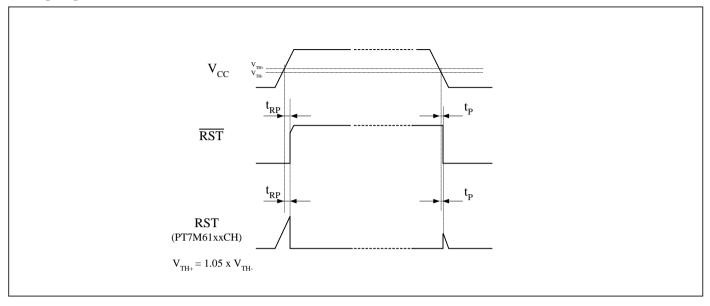
Description		Sym.	Test Conditions	Min	Тур	Max	Unit	
Supply Voltage		V	T _A = 0~70 ℃ 1.0		-	5.5	V	
		V_{CC}	T _A = -40~85 °C	5℃ 1.2 - 5.5		5.5	\ \ \ \ \ \ \ \	
Samuelas Casa			$V_{CC} = 3.6V$. No load.	-	1.0	3.0	μΑ	
Supply Current		I_{CC}	V _{CC} = 5V. No load 1.3		3.6	μА		
		V_{OH}	$V_{CC} \ge 1.8V$, $I_{source} = 1mA$	0.8×Vcc	-	-	V	
	Output high		$V_{CC} \ge 2.5 V$, $I_{source} = 3 \text{mA}$	0.8×Vcc	-	-		
Output			$V_{CC} \ge 4.5 \text{V}, I_{source} = 8 \text{mA}$	0.8×Vcc	-	-		
Driving	Output low	V_{OL}	$V_{CC} \ge 1.2V$, $I_{sink} = 1mA$	-	ı	0.3	V	
			$V_{CC} \ge 2.5V$, $I_{sink} = 4mA$	-	ı	0.3		
			$V_{CC} \ge 4.5V$, $I_{sink} = 9mA$	-	ı	0.4		
Open-Drain Current	Open-Drain Output Leakage		-	-	-	1	μΑ	
			+25°C	(V _{TH-}) ×0.985	V_{TH-}	(V _{TH-}) ×1.015	V	
Voltage Threshold		V_{TH-}	-40°C~85°C	(V _{TH-}) ×0.975	$V_{\text{TH-}}$	(V _{TH-}) ×1.025		
		V	+25°C	(V _{TH+}) ×0.985	$V_{\text{TH+}}$	(V _{TH+}) ×1.015	V	
		V_{TH+}	-40°C~85°C	(V _{TH+}) ×0.975	$V_{\text{TH+}}$	(V _{TH+}) ×1.025		
voltage threshold Hysteresis		$V_{ m HYST}$	$V_{HYST} = [(V_{TH+})-(V_{TH-})]/(V_{TH-})$	3	4.5	6	%	
		▼ HYST	×100%	-	1	-		

Note: $V_{TH+} = 1.05 \times V_{TH-}$ is voltage threshold when Vcc falls from high to low. V_{TH+} is voltage threshold when Vcc rises from low to high.



AC Electrical Characteristics

Timing diagram

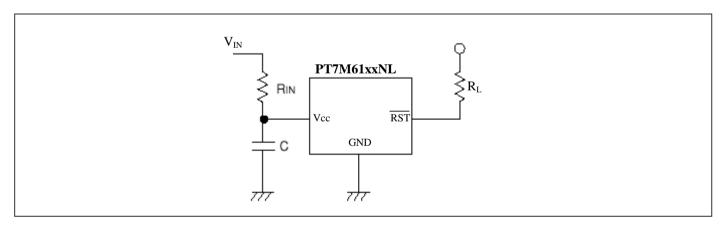


 $(V_{CC} = 1.2 \text{V to } 5.5 \text{V}, T_A = -40 \sim 85 \text{ C}, \text{ unless otherwise noted. Typical values are at } T_A = +25 \text{ C})$

Sym.	Description	Test Conditions	Min	Тур	Max	Unit
t_{RP}	Timeout Period	-	-	-	200	μs
t_{P}	Delay	-	-	50	-	μs
toverdrive	V _{CC} Maximum Transient Duration	Reset threshold overdrive=500mV (V _{CC} -V _{th} =-500mV)	-	20	-	μs

Typical Operation Circuit

PT7M61xxNL Application Example



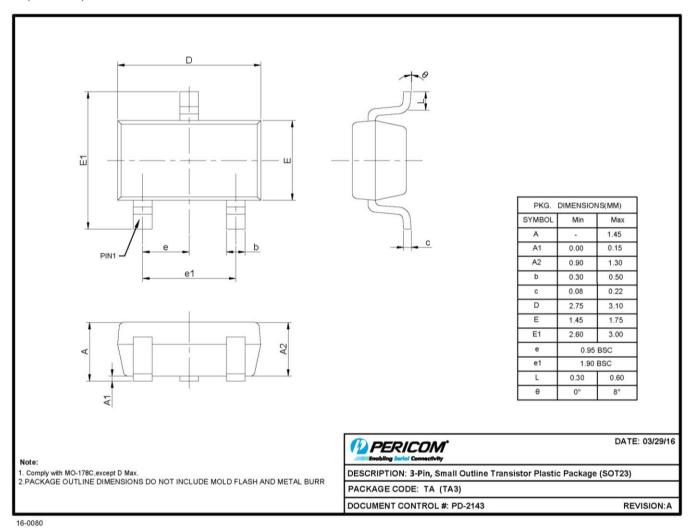
Please use N-ch open drains configuration, when a resistor $_{RIN}$ is connected between the V_{CC} pin and power source V_{IN} . In such cases, please ensure that R_{IN} is less than $10k\Omega$ and that C is more than $0.1\mu F$. R_L could be $1k\Omega$ to $510k\Omega$.





Mechanical Information

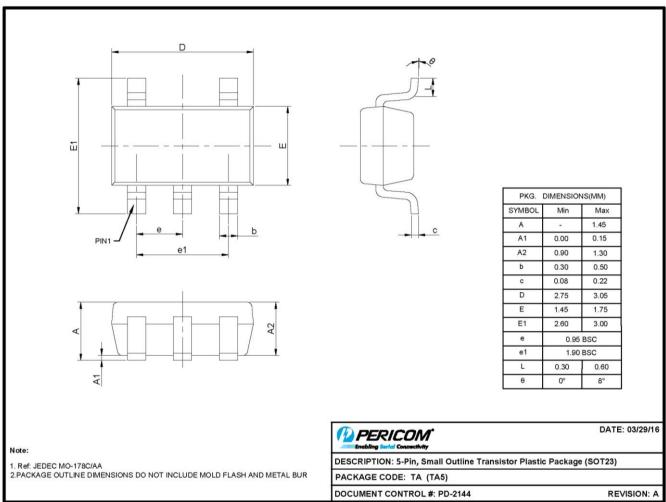
TA3 (SOT23-3)







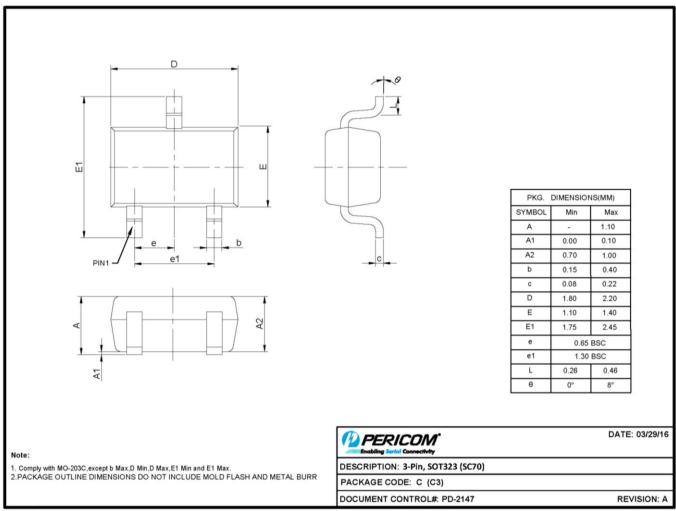
TA5 (SOT23-5)





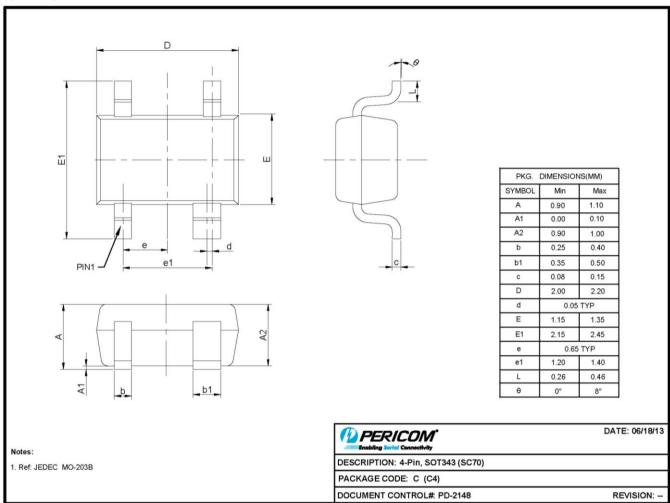


C3 (SC70-3)



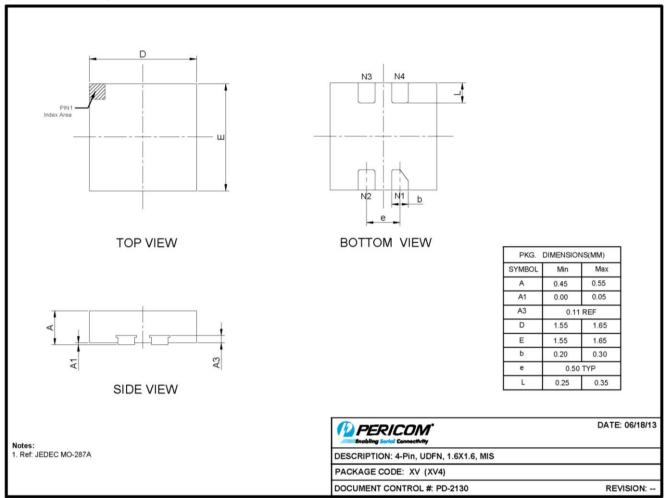


C4 (SC70-4)





XV (UDFN1.6x1.6-4L)





For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Part Number	Package Code	Package
PT7M61xxCLTA3E	TA3	3-Pin, Small Outline Transistor Plastic Package (SOT23)
PT7M61xxCLTA5E	TA5	5-Pin, Small Outline Transistor Plastic Package (SOT23)
PT7M61xxCLC3E	C3	3-Pin, SOT323 (SC70)
PT7M61xxCLC4E	C4	4-Pin, SOT343 (SC70)
*PT7M61xxCHTA3E	TA3	Lead free and Green SOT23-3
*PT7M61xxCHTA5E	TA5	5-Pin, Small Outline Transistor Plastic Package (SOT23)
*PT7M61xxCHC3E	C3	3-Pin, SOT323 (SC70)
*PT7M61xxCHC4E	C4	4-Pin, SOT343 (SC70)
PT7M61xxNLTA3E	TA3	3-Pin, Small Outline Transistor Plastic Package (SOT23)
PT7M61xxNLTA5E	TA5	5-Pin, Small Outline Transistor Plastic Package (SOT23)
PT7M61xxNLC3E	C3	3-Pin, SOT323 (SC70)
PT7M61xxNLC4E	C4	4-Pin, SOT343 (SC70)
PT7M61xxCLETA3E	TA3	3-Pin, Small Outline Transistor Plastic Package (SOT23)
PT7M61xxCLETA5E	TA5	5-Pin, Small Outline Transistor Plastic Package (SOT23)
PT7M61xxCLEC3E	C3	3-Pin, SOT323 (SC70)
PT7M61xxCLEC4E	C4	4-Pin, SOT343 (SC70)
*PT7M61xxCHETA3E	TA3	3-Pin, Small Outline Transistor Plastic Package (SOT23)
*PT7M61xxCHETA5E	TA5	5-Pin, Small Outline Transistor Plastic Package (SOT23)
*PT7M61xxCHEC3E	C3	3-Pin, SOT323 (SC70)
*PT7M61xxCHEC4E	C4	4-Pin, SOT343 (SC70)
PT7M61xxNLETA3E	TA3	3-Pin, Small Outline Transistor Plastic Package (SOT23)
PT7M61xxNLETA5E	TA5	5-Pin, Small Outline Transistor Plastic Package (SOT23)
PT7M61xxNLEC3E	C3	3-Pin, SOT323 (SC70)
PT7M61xxNLEC4E	C4	4-Pin, SOT343 (SC70)
PT7M61xxNLEXVE	XV	4-Pin, 1.6x1.6, MIS (UDFN)
PT7M61xxNLXVE	XV	4-Pin, 1.6x1.6, MIS (UDFN)
PT7M61xxCLXVE	XV	4-Pin, 1.6x1.6, MIS (UDFN)
PT7M61xxCLEXVE	XV	4-Pin, 1.6x1.6, MIS (UDFN)
*PT7M61xxCHXVE	XV	4-Pin, 1.6x1.6, MIS (UDFN)
*PT7M61xxCHEXVE	XV	4-Pin, 1.6x1.6, MIS (UDFN)

Notes:

- 1: "xx" refer to voltage range, see below table 1.
- 2: Adding E suffix=1% Hysteresis. For example: PT7M61xxCLETA3E.
- 3: None E suffix=5% Hysteresis. For example: PT7M61xxCLTA3E.
- 4: E = Pb-free and Green
- 5: Adding X Suffix= Tape/Reel
- 6: Contact Pericom for availability
- 7: "*" for CH part, please check the storage with related sales.





Table 1 Function comparison

Item			Reset			
	Part No.	Open	-Drain	Push-	Pull	Threshold
		Active high	Active low	Active high	Active low	
1	PT7M61xxCL	-	-	-	$\sqrt{}$	1.07/ (. 5.07/ . 100 . 7/
2	PT7M61xxCH	-	ı	V	-	1.8V to 5.0V in 100mV increments
3	PT7M61xxNL	-	V	-	-	merements

Table 2 Suffix "xx" definition of PT7M61xx

Suffix xx	$V_{TH-}(V)$	Suffix xx	$V_{TH-}(V)$	Suffix xx	V _{TH-} (V)	Suffix xx	V _{TH-} (V)	Suffix xx	$V_{TH-}(V)$
18	1.8	25	2.5	32	3.2	39	3.9	46	4.6
19	1.9	26	2.6	33	3.3	40	4.0	47	4.7
20	2.0	27	2.7	34	3.4	41	4.1	48	4.8
21	2.1	28	2.8	35	3.5	42	4.2	49	4.9
22	2.2	29	2.9	36	3.6	43	4.3	50	5.0
23	2.3	30	3.0	37	3.7	44	4.4		
24	2.4	31	3.1	38	3.8	45	4.5		



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